NSN 5961-01-354-0374

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Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

Between 0.691 inches and 0.835 inches

Overall Width:

Between 0.978 inches and 0.995 inches

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

T0-204

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Unthreaded hole

Features Provided:

Electrostatic sensitive and hermetically sealed case and quality assurance level tx

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

900.0 drain to gate voltage and 900.0 drain to source voltage and 20.0 gate to source voltage

Current Rating Per Characteristic:

11.00 amperes source cutoff current of standard range

Power Rating Per Characteristic:

250.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0